

Integrated Device Technology, Inc.

HIGH-SPEED 16K x 9 DUAL-PORT STATIC RAM

PRELIMINARY
IDT7016S/L

FEATURES:

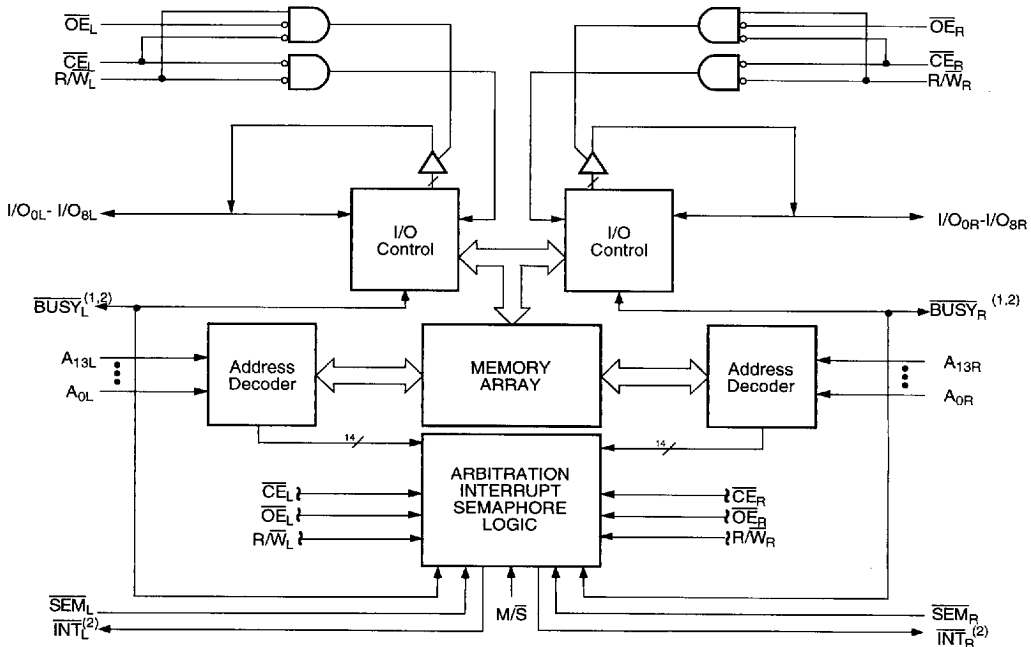
- True Dual-Ported memory cells which allow simultaneous reads of the same memory location
- High-speed access
 - Military: 25/35ns (max.)
 - Commercial: 15/17/20/25/35ns (max.)
- Low-power operation
 - IDT7016S
 - Active: 750mW (typ.)
 - Standby: 5mW (typ.)
 - IDT7016L
 - Active: 750mW (typ.)
 - Standby: 1mW (typ.)
- IDT7016 easily expands data bus width to 18 bits or more using the Master/Slave select when cascading more than one device
- M/S = H for \overline{BUSY} output flag on Master
M/S = L for \overline{BUSY} input on Slave

- Interrupt Flag
- On-chip port arbitration logic
- Full on-chip hardware support of semaphore signaling between ports
- Fully asynchronous operation from either port
- Devices are capable of withstanding greater than 2001V electrostatic discharge
- TTL-compatible, single 5V ($\pm 10\%$) power supply
- Available in ceramic 68-pin PGA, 68-pin PLCC, and an 80-pin TQFP
- Industrial temperature range (-40°C to $+85^{\circ}\text{C}$) is available, tested to military electrical specifications

DESCRIPTION:

The IDT7016 is a high-speed 16K x 9 Dual-Port Static RAMs. The IDT7016 is designed to be used as stand-alone 144K bit Dual-Port RAMs or as a combination MASTER/SLAVE Dual-Port RAM for 18-bit-or-more word systems.

FUNCTIONAL BLOCK DIAGRAM



NOTES:

1. In MASTER mode: \overline{BUSY} is an output and is a push-pull driver
In SLAVE mode: \overline{BUSY} is input.
2. \overline{BUSY} outputs and INT outputs are non-tristated push-pull drivers.

MILITARY AND COMMERCIAL TEMPERATURE RANGES

APRIL 1995

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Using the IDT MASTER/SLAVE Dual-Port RAM approach in 18-bit or wider memory system applications results in full-speed, error-free operation without the need for additional discrete logic.

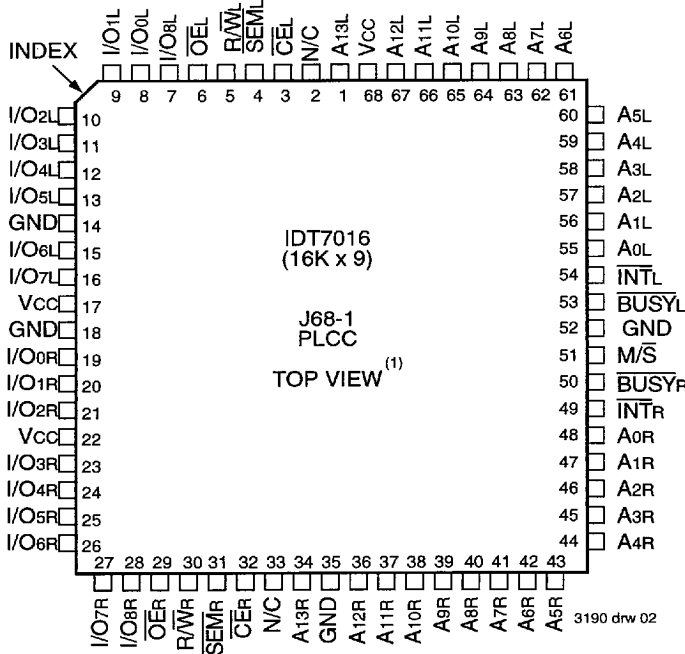
This device provides two independent ports with separate control, address, and I/O pins that permit independent, asynchronous access for reads or writes to any location in memory. An automatic power down feature controlled by \overline{CE} permits the on-chip circuitry of each port to enter a very low

standby power mode.

Fabricated using IDT's CMOS high-performance technology, these devices typically operate on only 750mW of power.

The IDT7016 is packaged in a ceramic 68-pin PGA, a 64-pin PLCC and an 80-pin TQFP (Thin Quad FlatPack). Military grade product is manufactured in compliance with the latest revision of MIL-STD-883, Class B, making it ideally suited to military temperature applications demanding the highest level of performance and reliability.

PIN CONFIGURATIONS



3190 drw 02

PIN NAMES (7016)

Left Port	Right Port	Names
\overline{CE}_L	\overline{CE}_R	Chip Enable
R/W _L	R/W _R	Read/Write Enable
\overline{OE}_L	\overline{OE}_R	Output Enable
A _{0L} - A _{13L}	A _{0R} - A _{13R}	Address
I/O _{0L} - I/O _{8L}	I/O _{0R} - I/O _{8R}	Data Input/Output
SEML	SEMR	Semaphore Enable
INT _L	INTR	Interrupt Flag
BUSYL	BUSYR	Busy Flag
M/ \overline{S}		Master or Slave Select
VCC ⁽¹⁾		Power
GND ⁽²⁾		Ground

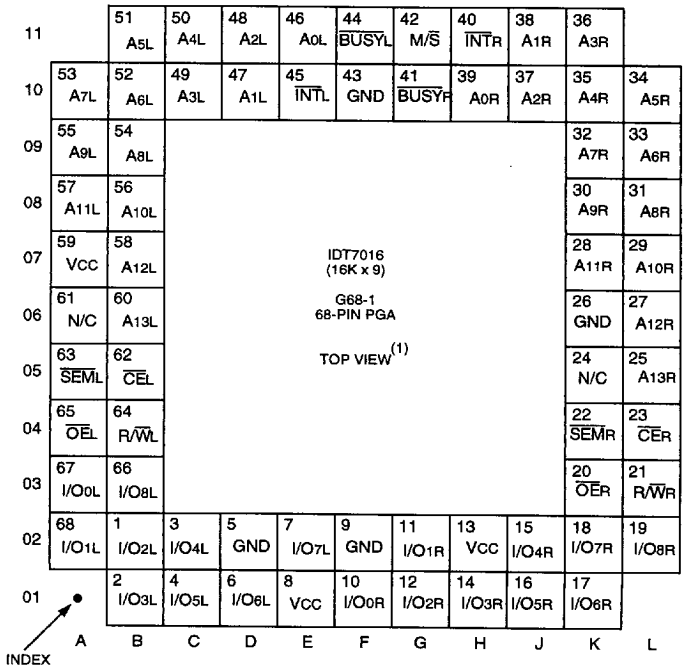
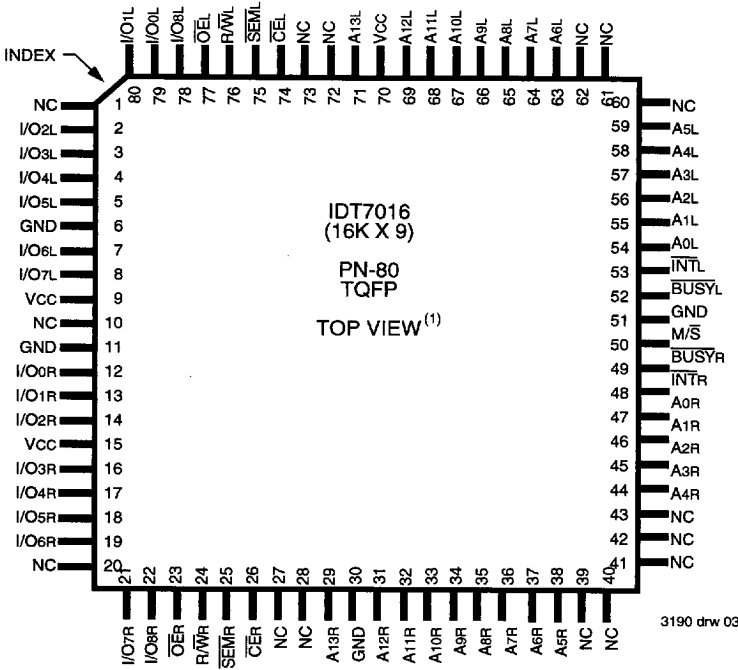
NOTES:

1. This text does not imply orientation of Part-Mark.

NOTES:

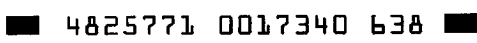
1. All Vcc pins must be connected to power supply.
2. All GND pins must be connected to ground supply.

3190 tbl 01



NOTES:
1. This text does not imply orientation of Part-Mark.

INDEX



TRUTH TABLE: NON-CONTENTION READ/WRITE CONTROL

Inputs ⁽¹⁾				Outputs	Mode
CE	R/W	OE	SEM	I/O ₀₋₈	
H	X	X	H	High-Z	Deselected: Power-Down
L	L	X	H	DATAin	Write to Memory
L	H	L	H	DATAout	Read Memory
X	X	H	X	High-Z	Outputs Disabled

NOTE:

1. Condition: A0L — A13L is not equal to A0R — A13R

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TRUTH TABLE: SEMAPHORE READ/WRITE CONTROL

Inputs				Outputs	Mode
CE	R/W	OE	SEM	I/O ₀₋₈	
H	H	L	L	DATAout	Read Semaphore Flag Data Out
H	✓	X	L	DATAin	Write I/O ₀ into Semaphore Flag
L	X	X	L	—	Not Allowed

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ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Rating	Commercial	Military	Unit
VTERM ⁽²⁾	Terminal Voltage with Respect to GND	-0.5 to +7.0	-0.5 to +7.0	V
TA	Operating Temperature	0 to +70	-55 to +125	°C
TBIAS	Temperature Under Bias	-55 to +125	-65 to +135	°C
TSTG	Storage Temperature	-55 to +125	-65 to +150	°C
IOUT	DC Output Current	50	50	mA

NOTES:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
- VTERM must not exceed Vcc + 0.5V for more than 25% of the cycle time or 10ns maximum, and is limited to ≤ 20mA for the period of VTERM ≥ Vcc + 0.5V.

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RECOMMENDED OPERATING TEMPERATURE AND SUPPLY VOLTAGE

Grade	Ambient Temperature	GND	Vcc
Military	-55°C to +125°C	0V	5.0V ± 10%
Commercial	0°C to +70°C	0V	5.0V ± 10%

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RECOMMENDED DC OPERATING CONDITIONS

Symbol	Parameter	Min.	Typ.	Max.	Unit
Vcc	Supply Voltage	4.5	5.0	5.5	V
GND	Supply Voltage	0	0	0	V
VIH	Input High Voltage	2.2	—	6.0 ⁽²⁾	V
VIL	Input Low Voltage	-0.5 ⁽¹⁾	—	0.8	V

NOTES:

- VIL ≥ -1.5V for pulse width less than 10ns.
- VTERM must not exceed Vcc + 0.5V.

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CAPACITANCE (TA = +25°C, f = 1.0MHz, for TQFP Package)⁽¹⁾

Symbol	Parameter	Conditions ⁽²⁾	Max.	Unit
CIN	Input Capacitance	VIN = 3dV	9	pF
COU	Output Capacitance	VOUT = 3dV	10	pF

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NOTES:

- This parameter is determined by device characteristics but is not production tested.
- 3dV references the interpolated capacitance when the input and output signals switch from 0V to 3V or from 3V to 0V.



DC ELECTRICAL CHARACTERISTICS OVER THE OPERATING TEMPERATURE AND SUPPLY VOLTAGE RANGE ($V_{CC} = 5.0V \pm 10\%$)

Symbol	Parameter	Test Conditions	7016 S		7016 L		Unit
			Min.	Max.	Min.	Max.	
II _{L1}	Input Leakage Current ⁽⁵⁾	$V_{CC} = 5.5V, V_{IN} = 0V$ to V_{CC}	—	10	—	5	μA
II _{L0}	Output Leakage Current	$\overline{CE} = V_{IH}, V_{OUT} = 0V$ to V_{CC}	—	10	—	5	μA
V _{OL}	Output Low Voltage	I _{OL} = 4mA	—	0.4	—	0.4	V
V _{OH}	Output High Voltage	I _{OH} = -4mA	2.4	—	2.4	—	V

NOTES:
At $V_{CC} = 2.0V$, Input leakages are undefined. 3190 tbl 09

DC ELECTRICAL CHARACTERISTICS OVER THE OPERATING TEMPERATURE AND SUPPLY VOLTAGE RANGE⁽¹⁾ ($V_{CC} = 5.0V \pm 10\%$)

Symbol	Parameter	Test Condition	Version	7016X15 COM'L ONLY		7016X17 COM'L ONLY		Unit
				Typ. ⁽²⁾	Max.	Typ. ⁽²⁾	Max.	
I _{CC}	Dynamic Operating Current (Both Ports Active)	$\overline{CE} = V_{IL}$, Outputs Open $SEM = V_{IH}$ $f = f_{MAX}$ ⁽³⁾	MIL. S	—	—	—	—	mA
			COM'L. S	170	310	170	310	
I _{SB1}	Standby Current (Both Ports — TTL Level Inputs)	$\overline{CE}_R = \overline{CE}_L = V_{IH}$ $SEM_R = SEM_L = V_{IH}$ $f = f_{MAX}$ ⁽³⁾	MIL. S	—	—	—	—	mA
			COM'L. S	25	60	25	60	
I _{SB2}	Standby Current (One Port — TTL Level Inputs)	$\overline{CE}'_A = V_{IL}$ and $\overline{CE}'_B = V_{IH}$ ⁽⁵⁾ Active Port Outputs Open $f = f_{MAX}$ ⁽³⁾ $SEM_R = SEM_L = V_{IH}$	MIL. S	—	—	—	—	mA
			COM'L. S	105	190	105	190	
I _{SB3}	Full Standby Current (Both Ports — All CMOS Level Inputs)	Both Ports \overline{CE}_L and $\overline{CE}_R \geq V_{CC} - 0.2V$ $V_{IN} \geq V_{CC} - 0.2V$ or $V_{IN} \leq 0.2V, f = 0$ ⁽⁴⁾ $SEM_R = SEM_L \geq V_{CC} - 0.2V$	MIL. S	—	—	—	—	mA
			COM'L. S	1.0	15	1.0	15	
I _{SB4}	Full Standby Current (One Port — All CMOS Level Inputs)	$\overline{CE}'_A \leq 0.2V$ and $\overline{CE}'_B \geq V_{CC} - 0.2V$ ⁽⁵⁾ $SEM_R = SEM_L \geq V_{CC} - 0.2V$ $V_{IN} \geq V_{CC} - 0.2V$ or $V_{IN} \leq 0.2V$ Active Port Outputs Open, $f = f_{MAX}$ ⁽³⁾	MIL. S	—	—	—	—	mA
			COM'L. S	100	170	100	170	

NOTES:
1. "X" in part numbers indicates power rating (S or L)
2. $V_{CC} = 5V, T_A = +25^\circ C$, and are not production tested. I_{CCDC} = 120mA(typ.)
3. At $f = f_{MAX}$, address and control lines (except Output Enable) are cycling at the maximum frequency read cycle of 1/trc, and using "AC Test Conditions" of input levels of GND to 3V.
4. $f = 0$ means no address or control lines change.
5. Port "A" may be either left or right port. Port "B" is the opposite of port "A". 3190 tbl 09

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DC ELECTRICAL CHARACTERISTICS OVER THE OPERATING TEMPERATURE AND SUPPLY VOLTAGE RANGE⁽¹⁾(Continued) ($V_{CC} = 5.0V \pm 10\%$)

Symbol	Parameter	Test Condition	Version	7016X20		7016X25		7016X35		Unit	
				Typ. ⁽²⁾	Max.	Typ. ⁽²⁾	Max.	Typ. ⁽²⁾	Max.		
I _{CC}	Dynamic Operating Current (Both Ports Active)	$\overline{CE} = V_{IL}$, Outputs Open $\overline{SEM} = V_{IH}$ $f = f_{MAX}^{(3)}$	MIL.	S	—	—	155	340	150	300	mA
				L	—	—	155	280	150	250	
			COM'L.	S	160	290	155	265	150	250	
				L	160	240	155	220	150	210	
I _{SB1}	Standby Current (Both Ports — TTL Level Inputs)	$\overline{CE}_L = \overline{CE}_R = V_{IH}$ $\overline{SEM}_R = \overline{SEM}_L = V_{IH}$ $f = f_{MAX}^{(3)}$	MIL.	S	—	—	16	80	13	80	mA
				L	—	—	16	65	13	65	
			COM'L.	S	20	60	16	60	13	60	
				L	20	50	16	50	13	50	
I _{SB2}	Standby Current (One Port — TTL Level Inputs)	$\overline{CE}^A = V_{IL}$ and $\overline{CE}^B = V_{IH}^{(5)}$ Active Port Outputs Open $f = f_{MAX}^{(3)}$ $\overline{SEM}_R = \overline{SEM}_L = V_{IH}$	MIL.	S	—	—	90	215	85	190	mA
				L	—	—	90	180	85	160	
			COM'L.	S	95	180	90	170	85	155	
				L	95	150	90	140	85	130	
I _{SB3}	Full Standby Current (Both Ports — All CMOS Level Inputs)	Both Ports \overline{CE}_L and $\overline{CE}_R \geq V_{CC} - 0.2V$ $V_{IN} \geq V_{CC} - 0.2V$ or $V_{IN} \leq 0.2V$, $f = 0^{(4)}$ $\overline{SEM}_R = \overline{SEM}_L \geq V_{CC} - 0.2V$	MIL.	S	—	—	1.0	30	1.0	30	mA
				L	—	—	0.2	10	0.2	10	
			COM'L.	S	1.0	15	1.0	15	1.0	15	
				L	0.2	5	0.2	5	0.2	5	
I _{SB4}	Full Standby Current (One Port — All CMOS Level Inputs)	$\overline{CE}^A \leq 0.2V$ and $\overline{CE}^B \geq V_{CC} - 0.2V^{(5)}$ $\overline{SEM}_R = \overline{SEM}_L \geq V_{CC} - 0.2V$ $V_{IN} \geq V_{CC} - 0.2V$ or $V_{IN} \leq 0.2V$ Active Port Outputs Open, $f = f_{MAX}^{(3)}$	MIL.	S	—	—	85	200	80	175	mA
				L	—	—	85	170	80	150	
			COM'L.	S	90	155	85	145	80	135	
				L	90	130	85	120	80	110	

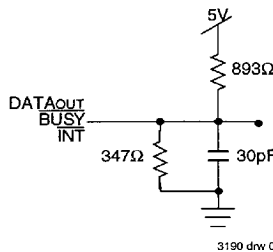
NOTES:

- "X" in part numbers indicates power rating (S or L)
- $V_{CC} = 5V$, $T_A = +25^\circ C$, and are not production tested. $I_{CCDC} = 120mA$ (typ.)
- At $f = f_{MAX}$, address and control lines (except Output Enable) are cycling at the maximum frequency read cycle of $1/RC$, and using "AC Test Conditions" of input levels of GND to 3V.
- $f = 0$ means no address or control lines change.
- Port "A" may be either left or right port. Port "B" is the opposite of port "A".

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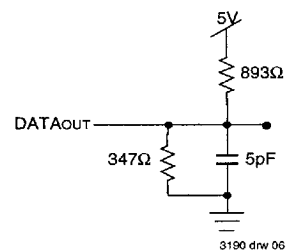
OUTPUT LOADS AND AC TEST CONDITIONS

Input Pulse Levels	GND to 3.0V
Input Rise/Fall Times	5ns Max.
Input Timing Reference Levels	1.5V
Output Reference Levels	1.5V
Output Load	Figure 1 & 2



3190 drw 05

Figure 1. AC Output Test Load



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Figure 2. Output Test Load (for t_{LZ}, t_{HZ}, t_{wz}, t_{ow}) including scope and jig.

**AC ELECTRICAL CHARACTERISTICS OVER THE
OPERATING TEMPERATURE AND SUPPLY VOLTAGE RANGE⁽⁴⁾**

Symbol	Parameter	IDT7016X15 COM'L ONLY		IDT7016X17 COM'L ONLY		Unit
		Min.	Max.	Min.	Max.	
READ CYCLE						
t _{RC}	Read Cycle Time	15	—	17	—	ns
t _{AA}	Address Access Time	—	15	—	17	ns
t _{ACE}	Chip Enable Access Time ⁽³⁾	—	15	—	17	ns
t _{AOE}	Output Enable Access Time	—	10	—	10	ns
t _{OH}	Output Hold from Address Change	3	—	3	—	ns
t _{LZ}	Output Low-Z Time ^(1, 2)	3	—	3	—	ns
t _{HZ}	Output High-Z Time ^(1, 2)	—	10	—	10	ns
t _{PU}	Chip Enable to Power Up Time ⁽²⁾	0	—	0	—	ns
t _{PD}	Chip Disable to Power Down Time ⁽²⁾	—	15	—	17	ns
t _{SOP}	Semaphore Flag Update Pulse (\overline{OE} or \overline{SEM})	10	—	10	—	ns
t _{SAA}	Semaphore Address Access Time	—	15	—	17	ns

Symbol	Parameter	IDT7016X20		IDT7016X25		IDT7016X35		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	
READ CYCLE								
t _{RC}	Read Cycle Time	20	—	25	—	35	—	ns
t _{AA}	Address Access Time	—	20	—	25	—	35	ns
t _{ACE}	Chip Enable Access Time ⁽³⁾	—	20	—	25	—	35	ns
t _{AOE}	Output Enable Access Time	—	12	—	13	—	20	ns
t _{OH}	Output Hold from Address Change	3	—	3	—	3	—	ns
t _{LZ}	Output Low-Z Time ^(1, 2)	3	—	3	—	3	—	ns
t _{HZ}	Output High-Z Time ^(1, 2)	—	12	—	15	—	20	ns
t _{PU}	Chip Enable to Power Up Time ⁽²⁾	0	—	0	—	0	—	ns
t _{PD}	Chip Disable to Power Down Time ⁽²⁾	—	20	—	25	—	35	ns
t _{SOP}	Semaphore Flag Update Pulse (\overline{OE} or \overline{SEM})	10	—	10	—	15	—	ns
t _{SAA}	Semaphore Address Access Time	—	20	—	25	—	35	ns

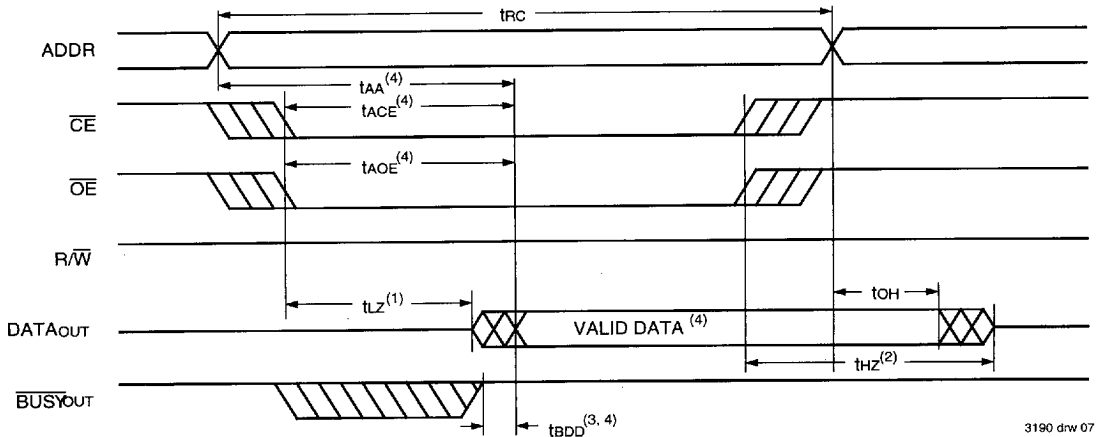
NOTES:

1. Transition is measured $\pm 500\text{mV}$ from low- or high-impedance voltage with load (Figures 1 and 2).
2. This parameter is guaranteed but not tested.
3. To access RAM, $\overline{CE} = V_{IL}$ and $\overline{SEM} = V_{IH}$. To access semaphore, $\overline{CE} = V_{IH}$ and $\overline{SEM} = V_{IL}$.
4. "X" in part numbers indicates power rating (S or L).

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WAVEFORM OF READ CYCLES⁽⁵⁾

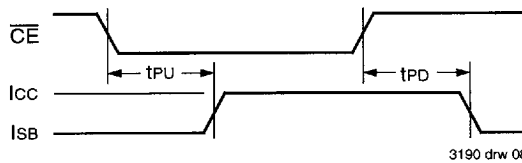


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NOTES:

1. Timing depends on which signal is asserted last, \overline{OE} or \overline{CE} .
2. Timing depends on which signal is de-asserted first, \overline{CE} or \overline{OE} .
3. t_{BDD} delay is required only in cases where the opposite port is completing a write operation to the same address location. For simultaneous read operations \overline{BUSY} has no relation to valid output data.
4. Start of valid data depends on which timing becomes effective last t_{AOE} , t_{ACE} , t_{AA} or t_{BDD} .
5. $\overline{SEM} = V_{IH}$.

TIMING OF POWER-UP / POWER-DOWN



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**AC ELECTRICAL CHARACTERISTICS OVER THE
OPERATING TEMPERATURE AND SUPPLY VOLTAGE⁽⁵⁾**

Symbol	Parameter	IDT7016X15 COM'L ONLY		IDT7016X17 COM'L ONLY		Unit
		Min.	Max.	Min.	Max.	
WRITE CYCLE						
tWC	Write Cycle Time	15	—	17	—	ns
tEW	Chip Enable to End-of-Write ⁽³⁾	12	—	12	—	ns
tAW	Address Valid to End-of-Write	12	—	12	—	ns
tAS	Address Set-up Time ⁽³⁾	0	—	0	—	ns
tWP	Write Pulse Width	12	—	12	—	ns
tWR	Write Recovery Time	2	—	2	—	ns
tdW	Data Valid to End-of-Write	12	—	10	—	ns
tHZ	Output High-Z Time ^(1, 2)	—	10	—	10	ns
tdH	Data Hold Time ⁽⁴⁾	0	—	0	—	ns
twZ	Write Enable to Output in High-Z ^(1, 2)	—	10	—	10	ns
tOW	Output Active from End-of-Write ^(1, 2, 4)	3	—	3	—	ns
tSWRD	$\overline{\text{SEM}}$ Flag Write to Read Time	5	—	5	—	ns
tSPS	$\overline{\text{SEM}}$ Flag Contention Window	5	—	5	—	ns

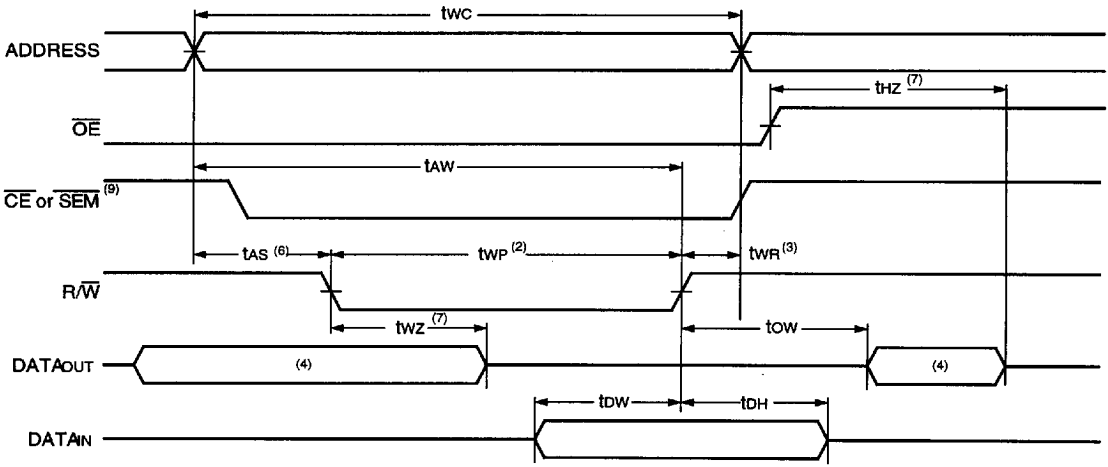
Symbol	Parameter	IDT7016X20		IDT7016X25		IDT7016X35		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	
WRITE CYCLE								
tWC	Write Cycle Time	20	—	25	—	35	—	ns
tEW	Chip Enable to End-of-Write ⁽³⁾	15	—	20	—	30	—	ns
tAW	Address Valid to End-of-Write	15	—	20	—	30	—	ns
tAS	Address Set-up Time ⁽³⁾	0	—	0	—	0	—	ns
tWP	Write Pulse Width	15	—	20	—	25	—	ns
tWR	Write Recovery Time	2	—	2	—	2	—	ns
tdW	Data Valid to End-of-Write	15	—	15	—	15	—	ns
tHZ	Output High-Z Time ^(1, 2)	—	12	—	15	—	20	ns
tdH	Data Hold Time ⁽⁴⁾	0	—	0	—	0	—	ns
twZ	Write Enable to Output in High-Z ^(1, 2)	—	12	—	15	—	20	ns
tOW	Output Active from End-of-Write ^(1, 2, 4)	3	—	3	—	3	—	ns
tSWRD	$\overline{\text{SEM}}$ Flag Write to Read Time	5	—	5	—	5	—	ns
tSPS	$\overline{\text{SEM}}$ Flag Contention Window	5	—	5	—	5	—	ns

- NOTES:** 3190 IBI 12
1. Transition is measured $\pm 500\text{mV}$ from low - or high-impedance voltage with the output test load (Figure 2).
 2. This parameter is guaranteed but not tested.
 3. To access RAM, $\overline{\text{CE}} = \text{VIL}$ and $\overline{\text{SEM}} = \text{VIH}$. To access semaphore, $\overline{\text{CE}} = \text{VIH}$ and $\overline{\text{SEM}} = \text{VIL}$. Either condition must be valid for the entire tEW time.
 4. The specification for tDH must be met by the device supplying write data to the RAM under all operating conditions. Although tDH and tOW values will vary over voltage and temperature, the actual tDH will always be smaller than the actual tOW.
 5. "X" in part numbers indicates power rating (S or L).

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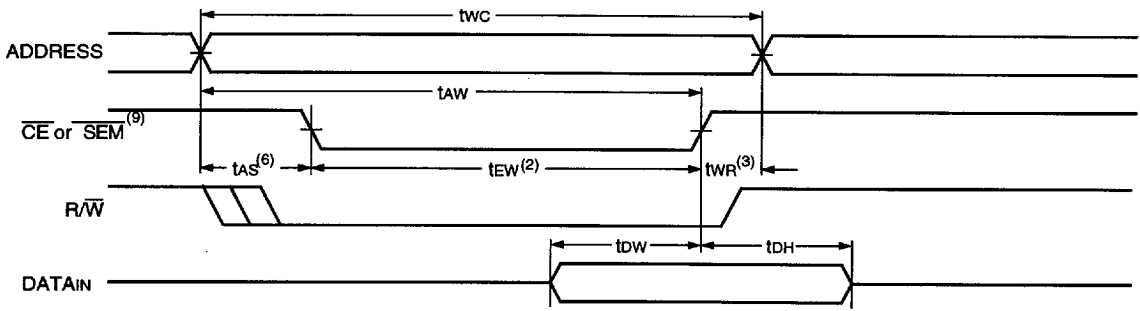
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TIMING WAVEFORM OF WRITE CYCLE NO. 1, R/W CONTROLLED TIMING^(1,5,8)



3190 drw 09

TIMING WAVEFORM OF WRITE CYCLE NO. 2, CE CONTROLLED TIMING^(1,5)

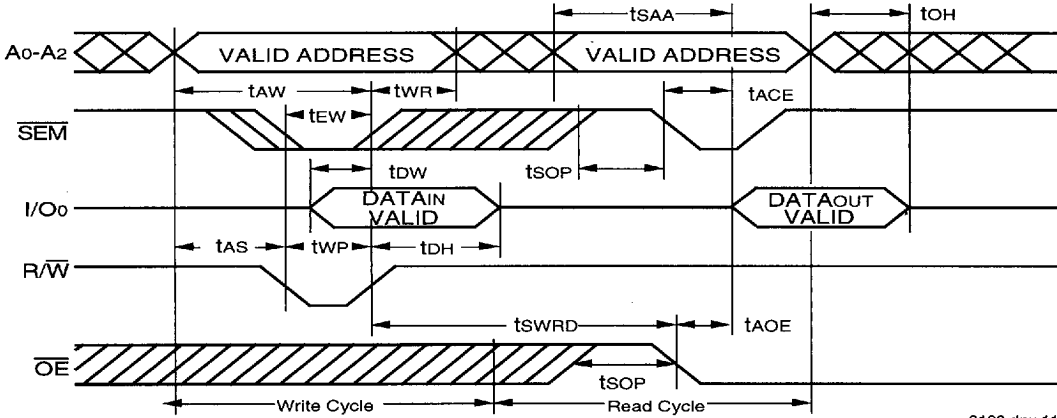


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NOTES:

1. R/W or CE must be high during all address transitions.
2. A write occurs during the overlap (tew or twp) of a low CE and a low R/W for memory array writing cycle.
3. twr is measured from the earlier of CE or R/W (or SEM or R/W) going high to the end of write cycle.
4. During this period, the I/O pins are in the output state and input signals must not be applied.
5. If the CE or SEM low transition occurs simultaneously with or after the R/W low transition, the outputs remain in the high impedance state.
6. Timing depends on which enable signal is asserted last, CE or R/W.
7. This parameter is guaranteed by device characterization but is not production tested, transition is measured +/-200mV from steady state with the Output Test load (Figure 2).
8. If OE is low during R/W controlled write cycle, the write pulse width must be the larger of twp or (twz + tow) to allow the I/O drivers to turn off and data to be placed on the bus for the required tow. If OE is high during an R/W controlled write cycle, this requirement does not apply and the write pulse can be as short as the specified twp.
9. To access RAM, CE = VIL and SEM = VIH. To access Semaphore, CE = VIH and SEM = VIL. tew must be met for either condition.

TIMING WAVEFORM OF SEMAPHORE READ AFTER WRITE TIMING, EITHER SIDE⁽¹⁾

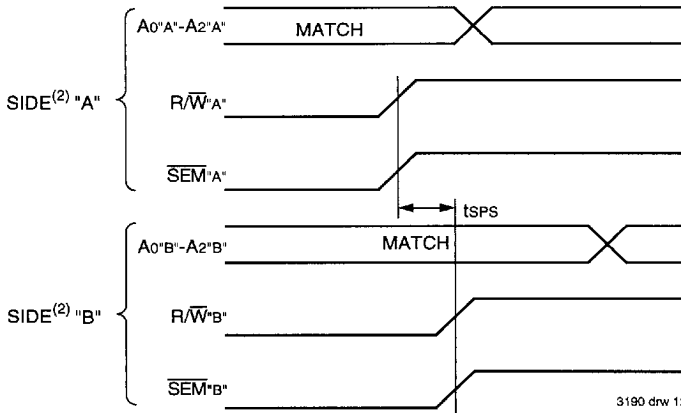


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NOTE:

1. $\overline{CE} = V_{IH}$ for the duration of the above timing (both write and read cycle).

TIMING WAVEFORM OF SEMAPHORE WRITE CONTENTION^(1,3,4)



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NOTES:

1. $D_{OR} = D_{OL} = V_{IH}$, $\overline{CE}_R = \overline{CE}_L = V_{IH}$.
2. All timing is the same for left and right ports. Port "A" may be either left or right port. "B" is the opposite port from "A".
3. This parameter is measured from R/\overline{W} or \overline{SEM}_A going high to R/\overline{W} s or \overline{SEM}_B s going High.
4. If tSPS is not satisfied, there is no guarantee which side will obtain the semaphore flag.

6

AC ELECTRICAL CHARACTERISTICS OVER THE OPERATING TEMPERATURE AND SUPPLY VOLTAGE RANGE⁽⁶⁾

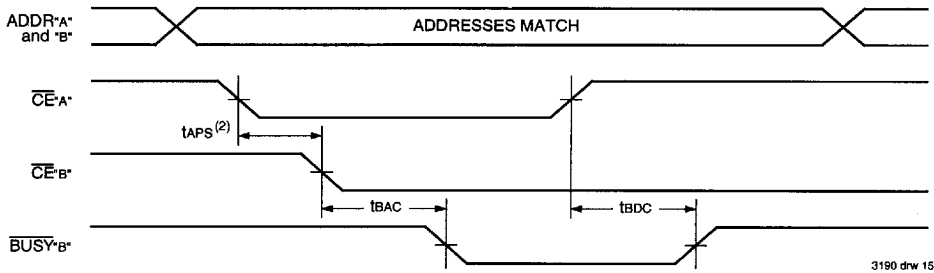
Symbol	Parameter	IDT7016X15 COM'L ONLY		IDT7016X17 COM'L ONLY		Unit
		Min.	Max.	Min.	Max.	
BUSY TIMING (M/S = H)						
tBAA	$\overline{\text{BUSY}}$ Access Time from Address Match	—	15	—	17	ns
tBDA	$\overline{\text{BUSY}}$ Disable Time from Address Not Matched	—	15	—	17	ns
tBAC	$\overline{\text{BUSY}}$ Access Time from Chip Enable LOW	—	15	—	17	ns
tBDC	$\overline{\text{BUSY}}$ Disable Time from Chip Enable HIGH	—	15	—	17	ns
tAPS	Arbitration Priority Set-up Time ⁽²⁾	5	—	5	—	ns
tBDD	$\overline{\text{BUSY}}$ Disable to Valid Data ⁽³⁾	—	15	—	17	ns
BUSY TIMING (M/S = L)						
tWB	$\overline{\text{BUSY}}$ Input to Write ⁽⁴⁾	0	—	0	—	ns
tWH	Write Hold After $\overline{\text{BUSY}}$ ⁽⁵⁾	13	—	13	—	ns
PORT-TO-PORT DELAY TIMING						
tWDD	Write Pulse to Data Delay ⁽¹⁾	—	30	—	30	ns
tDDD	Write Data Valid to Read Data Delay ⁽¹⁾	—	25	—	25	ns

Symbol	Parameter	IDT7016X20		IDT7016X25		IDT7016X35		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	
BUSY TIMING (M/S = H)								
tBAA	$\overline{\text{BUSY}}$ Access Time from Address Match	—	20	—	20	—	20	ns
tBDA	$\overline{\text{BUSY}}$ Disable Time from Address Not Matched	—	20	—	20	—	20	ns
tBAC	$\overline{\text{BUSY}}$ Access Time from Chip Enable LOW	—	20	—	20	—	20	ns
tBDC	$\overline{\text{BUSY}}$ Disable Time from Chip Enable HIGH	—	17	—	17	—	20	ns
tAPS	Arbitration Priority Set-up Time ⁽²⁾	5	—	5	—	5	—	ns
tBDD	$\overline{\text{BUSY}}$ Disable to Valid Data ⁽³⁾	—	20	—	25	—	35	ns
BUSY TIMING (M/S = L)								
tWB	$\overline{\text{BUSY}}$ Input to Write ⁽⁴⁾	0	—	0	—	0	—	ns
tWH	Write Hold After $\overline{\text{BUSY}}$ ⁽⁵⁾	15	—	17	—	25	—	ns
PORT-TO-PORT DELAY TIMING								
tWDD	Write Pulse to Data Delay ⁽¹⁾	—	45	—	50	—	60	ns
tDDD	Write Data Valid to Read Data Delay ⁽¹⁾	—	30	—	30	—	35	ns

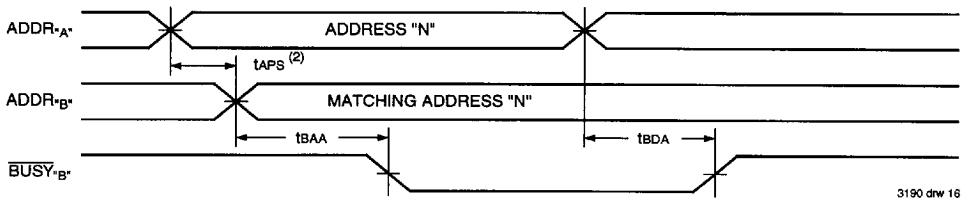
NOTES:

1. Port-to-port delay through RAM cells from writing port to reading port, refer to "Timing Waveform of Write with Port-to-Port Read and $\overline{\text{BUSY}}$ (M/S = V(H))".
2. To ensure that the earlier of the two ports wins.
3. tBDD is a calculated parameter and is the greater of 0, tWDD - tWP (actual) or tBDD - tWB (actual).
4. To ensure that the write cycle is inhibited on port "B" during contention on port "A".
5. To ensure that a write cycle is completed on port "B" after contention on port "A".
6. "X" in part numbers indicates power rating (S or L).

WAVEFORM OF BUSY ARBITRATION CONTROLLED BY \overline{CE} TIMING⁽¹⁾ ($M/\overline{S} = V_{IH}$)



WAVEFORM OF BUSY ARBITRATION CYCLE CONTROLLED BY ADDRESS MATCH TIMING⁽¹⁾ ($M/\overline{S} = V_{IH}$)



NOTES:

1. All timing is the same for left and right ports. Port "A" may be either the left or right port. Port "B" is the port opposite from "A".
2. If tAPS is not satisfied, the busy signal will be asserted on one side or another but there is no guarantee on which side busy will be asserted.

AC ELECTRICAL CHARACTERISTICS OVER THE OPERATING TEMPERATURE AND SUPPLY VOLTAGE RANGE⁽¹⁾

Symbol	Parameter	IDT7016X15 COM'L ONLY		IDT7016X17 COM'L ONLY		Unit
		Min.	Max.	Min.	Max.	
INTERRUPT TIMING						
tAS	Address Set-up Time	0	—	0	—	ns
tWR	Write Recovery Time	0	—	0	—	ns
tINS	Interrupt Set Time	—	15	—	17	ns
tINR	Interrupt Reset Time	—	15	—	17	ns

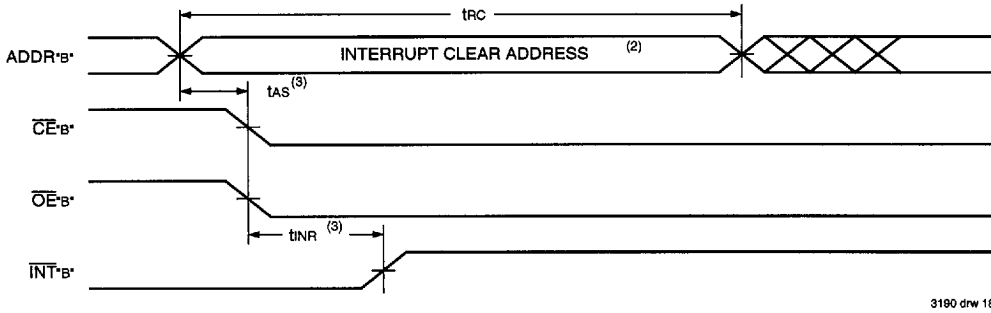
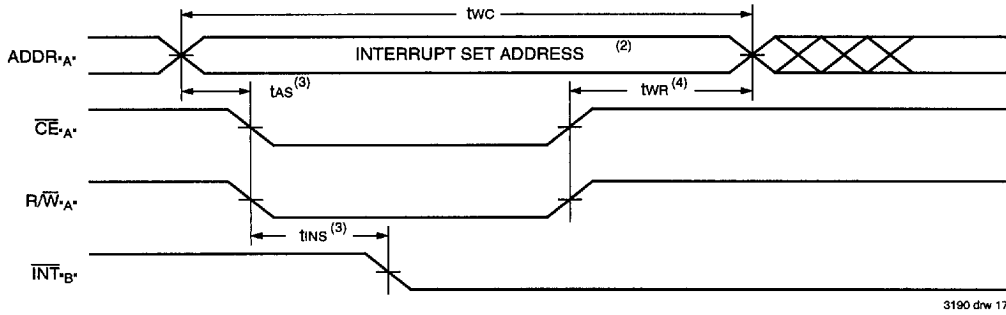
Symbol	Parameter	IDT7016X20		IDT7016X25		IDT7016X35		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	
INTERRUPT TIMING								
tAS	Address Set-up Time	0	—	0	—	0	—	ns
tWR	Write Recovery Time	0	—	0	—	0	—	ns
tINS	Interrupt Set Time	—	20	—	20	—	25	ns
tINR	Interrupt Reset Time	—	20	—	20	—	25	ns

NOTE:

1. "X" in part numbers indicates power rating (S or L).

2739 tbl 14

WAVEFORM OF INTERRUPT TIMING⁽¹⁾



NOTES:

1. All timing is the same for left and right ports. Port "A" may be either the left or right port. Port "B" is the port opposite from "A".
2. See Interrupt truth table.
3. Timing depends on which enable signal (CE or R/W) is asserted last.
4. Timing depends on which enable signal (CE or R/W) is de-asserted first.

TRUTH TABLES

TRUTH TABLE I — INTERRUPT FLAG⁽¹⁾

Left Port					Right Port					Function
R/W _L	CE _L	OE _L	A _{13L-A_{0L}}	INT _L	R/W _R	CE _R	OE _R	A _{13R-A_{0R}}	INT _R	
L	L	X	3FFF	X	X	X	X	X	L ⁽²⁾	Set Right INT _R Flag
X	X	X	X	X	X	L	L	3FFF	H ⁽³⁾	Reset Right INT _R Flag
X	X	X	X	L ⁽³⁾	L	L	X	3FFE	X	Set Left INT _L Flag
X	L	L	3FFE	H ⁽²⁾	X	X	X	X	X	Reset Left INT _L Flag

NOTES:

1. Assumes BUS_{YL} = BUS_{YR} = VIH.
2. If BUS_{YL} = VIL, then no change.
3. If BUS_{YR} = VIL, then no change.

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TRUTH TABLE II — ADDRESS BUSY ARBITRATION

Inputs			Outputs		Function
\overline{CE}_L	\overline{CE}_R	A0L-A13L A0R-A13R	BUSYL ⁽¹⁾	BUSYR ⁽¹⁾	
X	X	NO MATCH	H	H	Normal
H	X	MATCH	H	H	Normal
X	H	MATCH	H	H	Normal
L	L	MATCH	(2)	(2)	Write Inhibit ⁽³⁾

NOTES:

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1. Pins BUSYL and BUSYR are both outputs when the part is configured as a master. Both are inputs when configured as a slave. BUSYx outputs on the IDT7016 are push-pull, not open drain outputs. On slaves the BUSYx input internally inhibits writes.
2. "L" if the inputs to the opposite port were stable prior to the address and enable inputs of this port. "H" if the inputs to the opposite port became stable after the address and enable inputs of this port. If t_{APS} is not met, either BUSYL or BUSYR = Low will result. BUSYL and BUSYR outputs can not be low simultaneously.
3. Writes to the left port are internally ignored when BUSYL outputs are driving low regardless of actual logic level on the pin. Writes to the right port are internally ignored when BUSYR outputs are driving low regardless of actual logic level on the pin.

TRUTH TABLE III — EXAMPLE OF SEMAPHORE PROCUREMENT SEQUENCE⁽¹⁾

Functions	Do - Ds Left	Do - Ds Right	Status
No Action	1	1	Semaphore free
Left Port Writes "0" to Semaphore	0	1	Left port has semaphore token
Right Port Writes "0" to Semaphore	0	1	No change. Right side has no write access to semaphore
Left Port Writes "1" to Semaphore	1	0	Right port obtains semaphore token
Left Port Writes "0" to Semaphore	1	0	No change. Left port has no write access to semaphore
Right Port Writes "1" to Semaphore	0	1	Left port obtains semaphore token
Left Port Writes "1" to Semaphore	1	1	Semaphore free
Right Port Writes "0" to Semaphore	1	0	Right port has semaphore token
Right Port Writes "1" to Semaphore	1	1	Semaphore free
Left Port Writes "0" to Semaphore	0	1	Left port has semaphore token
Left Port Writes "1" to Semaphore	1	1	Semaphore free

NOTE:

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1. This table denotes a sequence of events for only one of the eight semaphores on the IDT7016.

FUNCTIONAL DESCRIPTION

The IDT7016 provides two ports with separate control, address and I/O pins that permit independent access for reads or writes to any location in memory. The IDT7016 has an automatic power down feature controlled by \overline{CE} . The \overline{CE} controls on-chip power down circuitry that permits the respective port to go into a standby mode when not selected (\overline{CE} High). When a port is enabled, access to the entire memory array is permitted.

memory location 3FFF and to clear the interrupt flag (\overline{INTR}), the right port must access memory location 3FFF. The message (9 bits) at 3FFE or 3FFF is user-defined since it is in an addressable SRAM location. If the interrupt function is not used, address locations 3FFE and 3FFF are not used as mail boxes but are still part of the random access memory. Refer to Table I for the interrupt operation.

INTERRUPTS

If the user chooses to use the interrupt function, a memory location (mail box or message center) is assigned to each port. The left port interrupt flag (\overline{INTL}) is asserted when the right port writes to memory location 3FFE where a write is defined as the $\overline{CE} = R/\overline{W} = V_{IL}$ per the Truth Table. The left port clears the interrupt by an address location 3FFE access when $\overline{CE}_R = \overline{OE}_R = V_{IL}$, R/\overline{W} is a "don't care". Likewise, the right port interrupt flag (\overline{INTR}) is asserted when the left port writes to

BUSY LOGIC

Busy Logic provides a hardware indication that both ports of the RAM have accessed the same location at the same time. It also allows one of the two accesses to proceed and signals the other side that the RAM is "busy". The busy pin can then be used to stall the access until the operation on the other side is completed. If a write operation has been attempted from the side that receives a busy indication, the write signal is gated internally to prevent the write from proceeding.

The use of busy logic is not required or desirable for all



Software handshaking between processors offers the maximum in system flexibility by permitting shared resources to be allocated in varying configurations. The IDT7016 does not use its semaphore flags to control any resources through hardware, thus allowing the system designer total flexibility in system architecture.

An advantage of using semaphores rather than the more common methods of hardware arbitration is that wait states are never incurred in either processor. This can prove to be a major advantage in very high-speed systems.

HOW THE SEMAPHORE FLAGS WORK

The semaphore logic is a set of eight latches which are independent of the Dual-Port RAM. These latches can be used to pass a flag, or token, from one port to the other to indicate that a shared resource is in use. The semaphores provide a hardware assist for a use assignment method called "Token Passing Allocation." In this method, the state of a semaphore latch is used as a token indicating that shared resource is in use. If the left processor wants to use this resource, it requests the token by setting the latch. This processor then verifies its success in setting the latch by reading it. If it was successful, it proceeds to assume control over the shared resource. If it was not successful in setting the latch, it determines that the right side processor has set the latch first, has the token and is using the shared resource. The left processor can then either repeatedly request that semaphore's status or remove its request for that semaphore to perform another task and occasionally attempt again to gain control of the token via the set and test sequence. Once the right side has relinquished the token, the left side should succeed in gaining control.

The semaphore flags are active low. A token is requested by writing a zero into a semaphore latch and is released when the same side writes a one to that latch.

The eight semaphore flags reside within the IDT7016 in a separate memory space from the Dual-Port RAM. This address space is accessed by placing a low input on the \overline{SEM} pin (which acts as a chip select for the semaphore flags) and using the other control pins (Address, \overline{OE} , and R/\overline{W}) as they would be used in accessing a standard static RAM. Each of the flags has a unique address which can be accessed by either side through address pins A0–A2. When accessing the semaphores, none of the other address pins has any effect.

When writing to a semaphore, only data pin Do is used. If a low level is written into an unused semaphore location, that flag will be set to a zero on that side and a one on the other side (see Table III). That semaphore can now only be modified by the side showing the zero. When a one is written into the same location from the same side, the flag will be set to a one for both sides (unless a semaphore request from the other side is pending) and then can be written to by both sides. The fact that the side which is able to write a zero into a semaphore subsequently locks out writes from the other side is what makes semaphore flags useful in interprocessor communications. (A thorough discussing on the use of this feature follows shortly.) A zero written into the same location from the other side will be stored in the semaphore request latch for that side

until the semaphore is freed by the first side.

When a semaphore flag is read, its value is spread into all data bits so that a flag that is a one reads as a one in all data bits and a flag containing a zero reads as all zeros. The read value is latched into one side's output register when that side's semaphore select (\overline{SEM}) and output enable (\overline{OE}) signals go active. This serves to disallow the semaphore from changing state in the middle of a read cycle due to a write cycle from the other side. Because of this latch, a repeated read of a semaphore in a test loop must cause either signal (\overline{SEM} or \overline{OE}) to go inactive or the output will never change.

A sequence WRITE/READ must be used by the semaphore in order to guarantee that no system level contention will occur. A processor requests access to shared resources by attempting to write a zero into a semaphore location. If the semaphore is already in use, the semaphore request latch will contain a zero, yet the semaphore flag will appear as one, a fact which the processor will verify by the subsequent read (see Table III). As an example, assume a processor writes a zero to the left port at a free semaphore location. On a subsequent read, the processor will verify that it has written successfully to that location and will assume control over the resource in question. Meanwhile, if a processor on the right side attempts to write a zero to the same semaphore flag it will fail, as will be verified by the fact that a one will be read from that semaphore on the right side during subsequent read. Had a sequence of READ/WRITE been used instead, system contention problems could have occurred during the gap between the read and write cycles.

It is important to note that a failed semaphore request must be followed by either repeated reads or by writing a one into the same location. The reason for this is easily understood by looking at the simple logic diagram of the semaphore flag in Figure 4. Two semaphore request latches feed into a semaphore flag. Whichever latch is first to present a zero to the semaphore flag will force its side of the semaphore flag low and the other side high. This condition will continue until a one is written to the same semaphore request latch. Should the other side's semaphore request latch have been written to a zero in the meantime, the semaphore flag will flip over to the other side as soon as a one is written into the first side's request latch. The second side's flag will now stay low until its semaphore request latch is written to a one. From this it is easy to understand that, if a semaphore is requested and the processor which requested it no longer needs the resource, the entire system can hang up until a one is written into that semaphore request latch.

The critical case of semaphore timing is when both sides request a single token by attempting to write a zero into it at the same time. The semaphore logic is specially designed to resolve this problem. If simultaneous requests are made, the logic guarantees that only one side receives the token. If one side is earlier than the other in making the request, the first side to make the request will receive the token. If both requests arrive at the same time, the assignment will be arbitrarily made to one port or the other.

One caution that should be noted when using semaphores is that semaphores alone do not guarantee that access to a

resource is secure. As with any powerful programming technique, if semaphores are misused or misinterpreted, a software error can easily happen.

Initialization of the semaphores is not automatic and must be handled via the initialization program at power-up. Since any semaphore request flag which contains a zero must be reset to a one, all semaphores on both sides should have a one written into them at initialization from both sides to assure that they will be free when needed.

USING SEMAPHORES—SOME EXAMPLES

Perhaps the simplest application of semaphores is their application as resource markers for the IDT7016's Dual-Port RAM. Say the 16K x 9 RAM was to be divided into two 8K x 9 blocks which were to be dedicated at any one time to servicing either the left or right port. Semaphore 0 could be used to indicate the side which would control the lower section of memory, and Semaphore 1 could be defined as the indicator for the upper section of memory.

To take a resource, in this example the lower 8K of Dual-Port RAM, the processor on the left port could write and then read a zero into Semaphore 0. If this task were successfully completed (a zero was read back rather than a one), the left processor would assume control of the lower 8K. Meanwhile the right processor was attempting to gain control of the resource after the left processor, it would read back a one in response to the zero it had attempted to write into Semaphore 0. At this point, the software could choose to try and gain control of the second 8K section by writing, then reading a zero into Semaphore 1. If it succeeded in gaining control, it would lock out the left side.

Once the left side was finished with its task, it would write a one to Semaphore 0 and may then try to gain access to Semaphore 1. If Semaphore 1 was still occupied by the right side, the left side could undo its semaphore request and perform other tasks until it was able to write, then read a zero

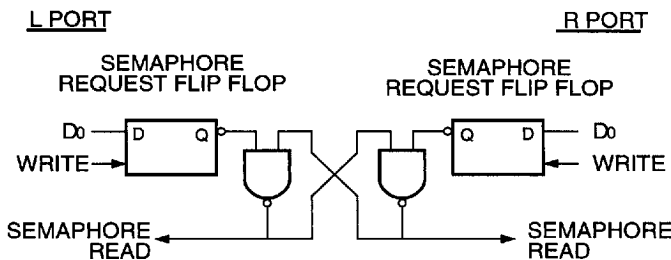
into Semaphore 1. If the right processor performs a similar task with Semaphore 0, this protocol would allow the two processors to swap 8K blocks of Dual-Port RAM with each other.

The blocks do not have to be any particular size and can even be variable, depending upon the complexity of the software using the semaphore flags. All eight semaphores could be used to divide the Dual-Port RAM or other shared resources into eight parts. Semaphores can even be assigned different meanings on different sides rather than being given a common meaning as was shown in the example above.

Semaphores are a useful form of arbitration in systems like disk interfaces where the CPU must be locked out of a section of memory during a transfer and the I/O device cannot tolerate any wait states. With the use of semaphores, once the two devices has determined which memory area was "off-limits" to the CPU, both the CPU and the I/O devices could access their assigned portions of memory continuously without any wait states.

Semaphores are also useful in applications where no memory "WAIT" state is available on one or both sides. Once a semaphore handshake has been performed, both processors can access their assigned RAM segments at full speed.

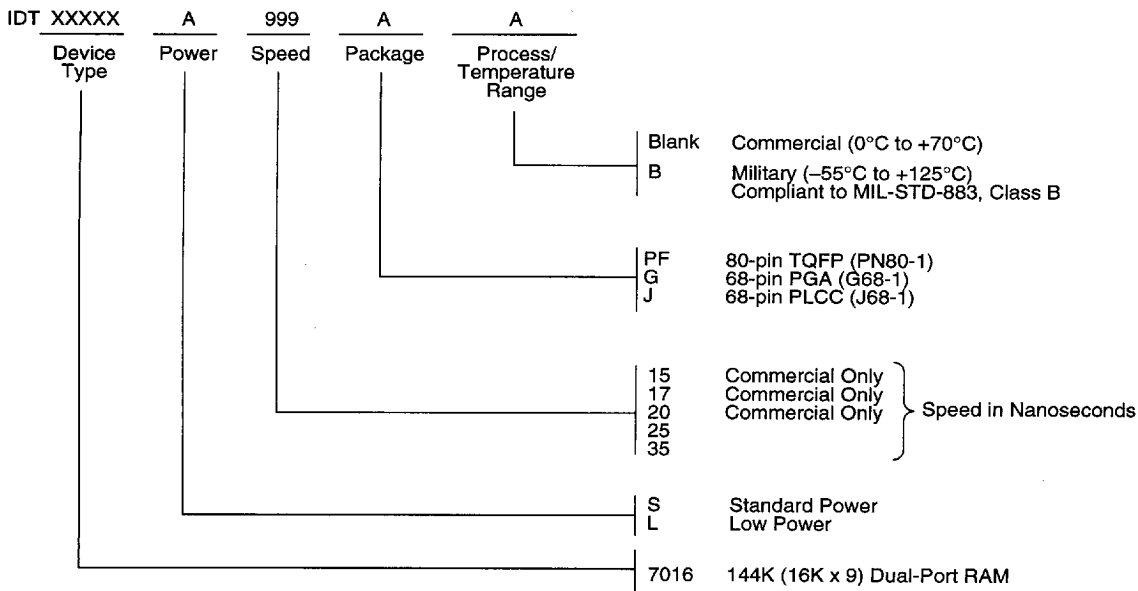
Another application is in the area of complex data structures. In this case, block arbitration is very important. For this application one processor may be responsible for building and updating a data structure. The other processor then reads and interprets that data structure. If the interpreting processor reads an incomplete data structure, a major error condition may exist. Therefore, some sort of arbitration must be used between the two different processors. The building processor arbitrates for the block, locks it and then is able to go in and update the data structure. When the update is completed, the data structure block is released. This allows the interpreting processor to come back and read the complete data structure, thereby guaranteeing a consistent data structure.



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Figure 4. IDT7016 Semaphore Logic

ORDERING INFORMATION



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